

Features

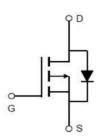
• -60V, -26A

$$\begin{split} &R_{DS\ (ON)} < 29m\ \Omega\ @V_{GS} = -10V & TYP:24m\ \Omega \\ &R_{DS\ (ON)} < 39m\ \Omega\ @V_{GS} = -4.5V & TYP:30.4m\ \Omega \end{split}$$

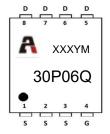
- Advanced Trench Technology
- High Power and current handing capability
- Lead free product is acquired

Applications

- Load Switch
- DC/DC converter for LCD display



Schematic Diagram



Package Marking and Ordering Information

Marking and pin Assignment

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity (PCS)
30P06Q	AP30P06Q	PDFN3X3	13inch	-	5000

ABSOLUTE MAXIMUM RATINGS (T_J=25℃ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-60	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current (T _C =25℃)	I _D	-26	Α
Continuous Drain Current (T _C =100℃)	I _D	-16	Α
Pulsed Drain Current (1)	I _{DM}	-104	Α
Single Pulsed Avalanche Energy (2)	E _{AS}	196	mJ
Drain Power Dissipation	P _D	33	W
Thermal Resistance from Junction to Case ⁽²⁾	R _{θJC}	3.7	°C/W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	60	°C/W
Junction Temperature	TJ	150	$^{\circ}$
Storage Temperature	T _{STG}	-55~ +150	$^{\circ}$ C



MOSFET ELECTRICAL CHARACTERISTICS(T_J=25℃ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Туре	Max	Unit	
Static Characteristics							
Drain-source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = -250\mu A$	-60	-	-	V	
Zero gate voltage drain current	I _{DSS}	V _{DS} =-60V, V _{GS} = 0V	-	-	-1	μA	
Gate-body leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	-	-	±100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	-1.0	-1.8	-2.5	V	
Drain-source on-resistance ⁽³⁾	Б.	V _{GS} =-10V, I _D =-15A	-	24	29	mΩ	
Diam-source on-resistance*	R _{DS(on)}	V _{GS} =-4.5V, I _D =-10A		30.4	39	mΩ	
Dynamic characteristics	Dynamic characteristics						
Input Capacitance	C _{iss}		-	4026	-	pF	
Output Capacitance	Coss	V _{DS} =-25V, V _{GS} =0V, f =1.0MHz	-	134	-		
Reverse Transfer Capacitance	C _{rss}		-	98	-		
Switching characteristics							
Turn-on delay time	t _{d(on)}		-	12.2	-		
Turn-on rise time t _r		V_{DS} =-30 V , R_L =1.5 Ω ,	-	10	-	20	
Turn-off delay time	t _{d(off)}	$R_G=3\Omega$, $V_G=-10V$	-	64	-	ns	
Turn-off fall time	t _f		-	14	-		
Total Gate Charge	Qg	V 20V I 20A	-	68	-	nC	
Gate-Source Charge	Qgs	V _{DS} =-30V, I _D =-20A, V _{GS} =-10V	-	10.5	-		
Gate-Drain Charge	Qgd	VGS=-10V	-	13	-		
Source-Drain Diode characteristics							
Diode Forward voltage ⁽¹⁾ V _{SD}		T _J =25°C, V _{GS} =0V, I _S =-15A	-	-	-1.2	V	
Diode Forward current I _S		T _C =25℃	-	-	-26	А	
Body Diode Reverse Recovery Time	trr	T _J =25℃,IF=-20A,di/dt=100A/us		26		ns	
Body Diode Reverse Recovery Charge	Qrr	T _J =25℃, IF=-20A,di/dt=100A/us		29		nc	

Notes:

a) Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

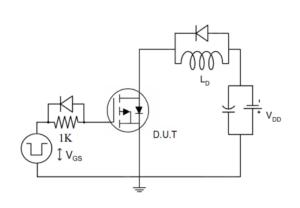
b) EAS condition: TJ=25 $^{\circ}$ C, VDD=-40V, VG=-10V, RG=25 Ω , L=0.5mH

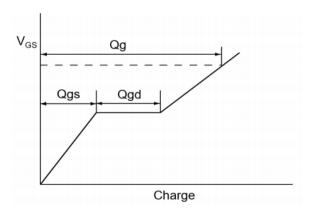
c) Pulse Test: Pulse Width≤300µs, Duty Cycle≤0.5%



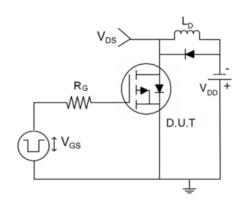
Test Circuit

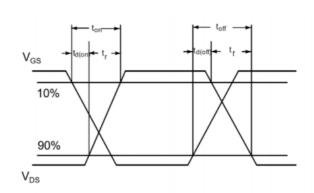
Gate Charge Test Circuit



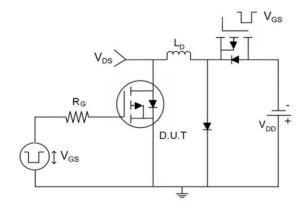


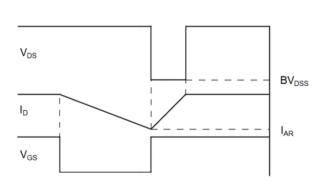
Switch Time Test Circuit





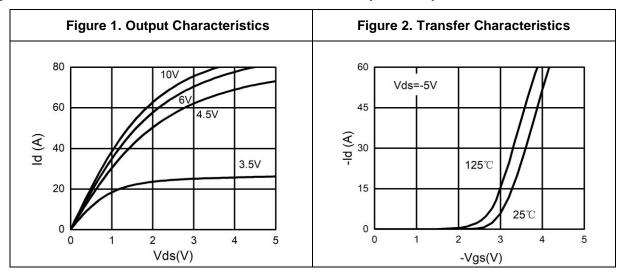
Unclamped Inductive Switching (UIS) Test Circuit

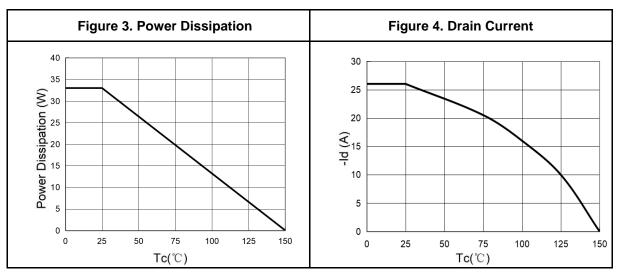


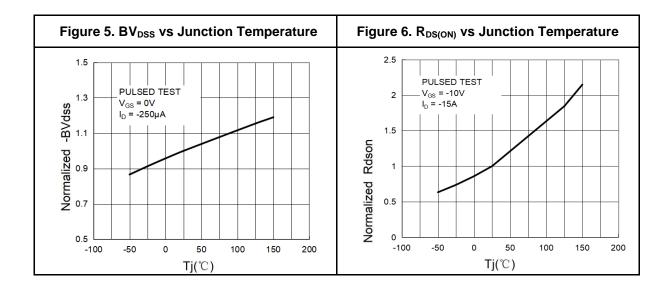




Typical Electrical And Thermal Characteristics (Curves)

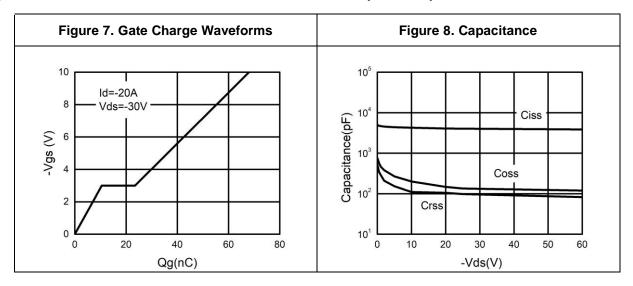


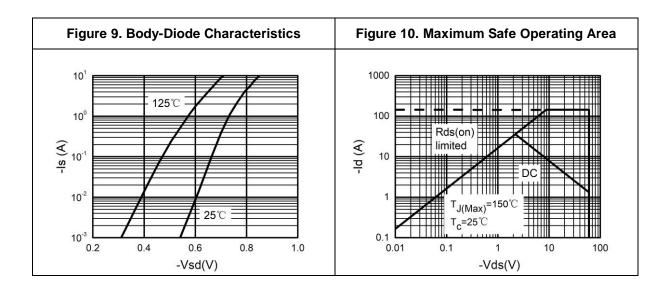






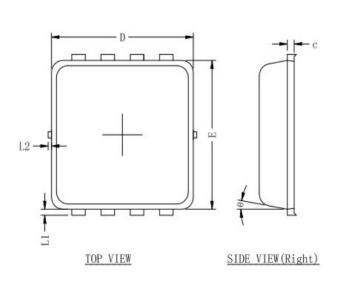
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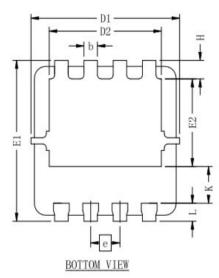


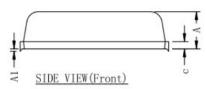




PDFN3X3 Package Information







SYMBOL	MIN.	NOM.	MAX.
Α	0.725	0.775	0.825
A1	0.000		0.050
b	0. 250	0.300	0.350
С	0.100	0.150	0.250
D	3. 050	3. 150	3. 250
Е	3.000	3. 100	3. 200
D1	3. 200	3. 300	3. 400
E1	3. 250	3. 350	3. 450
D2	2.350	2. 490	2. 590
E2	1. 685	1.825	1.925
е		0. 650 BSC.	
Н	0. 285	0. 385	0.485
L	0.300	0.375	0.475
L1	0.050	0. 125	0. 225
L2	0.000	0.075	0.130
K	0.200	0.765	(
θ	8°	10°	12°



Revision History

Revision	Release	Remark	
V1.0	2024/2/28	Initial Release	

Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Allpower assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which

requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.